

# Study of Vortex Dynamics in $V_{0.001}NbSe_2$ Superconductor

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**Abstract:** Large single crystals of  $V_{0.001}NbSe_2$  superconductor were synthesized using chemical vapour transport method. The vortex dynamics of this compound is evaluated in terms of critical current density ( $J_c$ ) and pinning force density ( $F_p$ ) characteristics.  $J_c$  shows a remarkably high value which indicates the presence of collective pinning of vortices. The superconducting transition temperature is suppressed to lower value in  $V_{0.001}NbSe_2$ . The normalized pinning force response with reduced magnetic field follows the Dew-Hugh's and Kramer's law, indicating the presence of both surface pinning and point pinning centers in this material.

## INTRODUCTION

Two dimensional superconductors now emerge as one of the most attracting class of materials because of its diverse intriguing properties [1]. Among them,  $NbSe_2$ , a 2D transitional metal dichalcogenides (TMDs) low transition temperature ( $T_c$ ) superconductors, provide a promising material platform for investigating various richly correlated electronic phases [2, 3].  $NbSe_2$  consists of one Nb layer sandwiched between two Se layers have been investigated enormously both in theoretical and experimental condensed matter physics owing to its essentially anisotropic properties [4]. Until now, many elements i.e. Fe, Cu, Sn, Mn, Co, Te, and Cr have been incorporated into the octahedral position of the Van de Waals gap between two NbSe layers, which results in suppression of superconductivity in  $NbSe_2$  [5-10]. Besides that, the coexistence of superconductivity and ferromagnetism has been also reported in hydrazine treated  $NbSe_2$  [11]. It is demonstrated that hydrazine treated  $NbSe_2$  leads to the modification of Nb-Se interaction and results in short range ferromagnetism with  $T_c \sim 6.8$  K. These results are significant for understanding the mechanism behind the superconductivity of anisotropic, layered low  $T_c$  as well as high  $T_c$  materials. This could shed new light on promising pathways to increase the  $T_c$  values and novel phases into the vortex dynamics of superconductor.

Here we study the effect of V atoms on  $T_c$  and vortex dynamics of  $NbSe_2$  through magnetization measurement to improve the practical applicability of low  $T_c$  superconductor. We have estimated critical current density ( $J_c$ ) and pinning force density ( $F_p$ ) to give better insight into the microscopic origin of the pinning mechanism in  $V_{0.001}NbSe_2$ .

## EXPERIMENTAL DETAILS

To grow large single crystal of  $V_{0.001}NbSe_2$ , chemical vapour transport method is used. High purity starting material Nb (99.8%), Se (99.999%), and V (99.99%) were weighed in proper stoichiometric ratio and well-grounded to make circular pellets of 1.3 cm diameter. The pellets were then sealed into an evacuated ( $5 \times 10^{-5}$  Torr) quartz tube and heated in a two zone furnace. The size of the crystal is  $2 \times 3 \times 0.1$  mm<sup>3</sup>. The obtained samples were characterized by Rigaku Smartlab powder X-ray diffractometer with Cu  $K_\alpha$  radiation at room temperature. Magnetic properties were measured using a Physical properties measurement system (PPMS-VSM) (Quantum Design) at ambient condition.

## RESULTS AND DISCUSSIONS

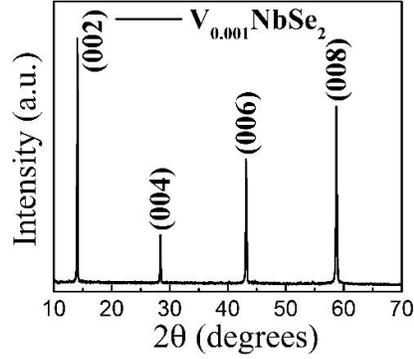


Figure 1. Xrd pattern of  $V_{0.001}NbSe_2$ .

The X-ray diffraction pattern of  $V_{0.001}NbSe_2$  is presented in Fig. 1. This shows hexagonal phase with space group 194-P63/mmc which is confirmed from JCPDS card no. 01-070-5612. The presence of (00 $l$ ) planes confirm the formation of single crystal of  $V_{0.001}NbSe_2$ .

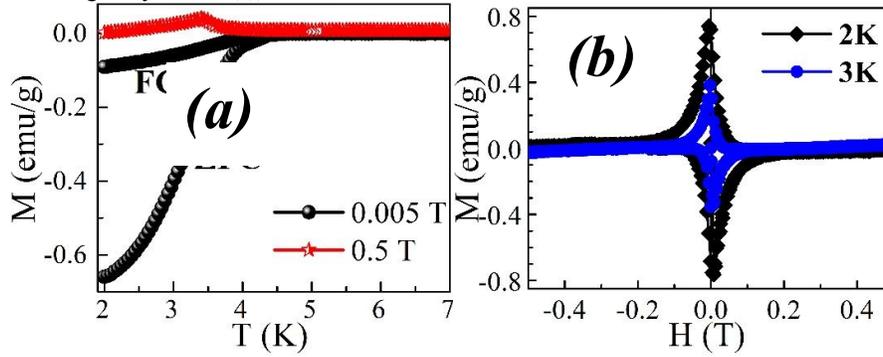


Figure 2. (a) Temperature dependence of magnetization curves in  $V_{0.001}NbSe_2$  under 0.005 T and 0.5 T for FC and ZFC measurements (b) Isothermal hysteresis loops (M-H) of  $V_{0.001}NbSe_2$  at 2 K and 3 K.

The characterization of the superconducting properties of  $V_{0.001}NbSe_2$  have been done by temperature dependent magnetization measurement with the magnetic field of  $H=0.005T$  and  $0.5 T$  as shown in Fig. 2 (a) following zero field cooling (ZFC) and field cooling (FC) process. The magnetization curves show a sharp drop at low temperature indicating the onset of superconductivity. The superconducting transition temperature,  $T_c$ , estimated at the point of deviation of ZFC curve from zero magnetization value, is about 4.6 K for  $V_{0.001}NbSe_2$ . This result implies that the superconductivity is suppressed in  $V_{0.001}NbSe_2$  compare to  $NbSe_2$ , which follows  $Fe_xNbSe_2$  and  $Cr_xNbSe_2$  as reported to our previous paper [6, 7]. The reason behind the reduction of  $T_c$  in  $V_{0.001}NbSe_2$  may be due to the depletion of density of electronic states at Fermi energy level [5].

Further, the isothermal hysteresis loops (M-H) for  $V_{0.001}NbSe_2$  at 2 K and 3 K are represented in Fig. 2 (b). The M-H curves reveal the irreversible asymmetric behaviour indicating the dominating Bean-Livingstone (B-L) surface barrier effect. Following the M-H curves, intergrain  $J_c$  is calculated from Bean model [12, 13] using the following equation:

$$J_c = \frac{20 \Delta M}{b[1-(b/3a)]}, \quad a > b \quad (1)$$

Where  $\Delta M$  is the width of the M-H hysteresis loop and  $a$ , and  $b$  are the sample dimensions. However, Fig. 3 (a) shows the  $J_c$  curves of  $V_{0.001}NbSe_2$  that are estimated from eq. 1 at 2 K and 3 K temperatures. The determined value of  $J_{c, \max}$  at 2 K is about  $3 \times 10^5 A/m^2$  for  $V_{0.001}NbSe_2$  and after that  $J_c$  decreases monotonically with increasing magnetic field. This infers the collective creep of magnetic flux lines in the vortex lattice of  $V_{0.001}NbSe_2$ .

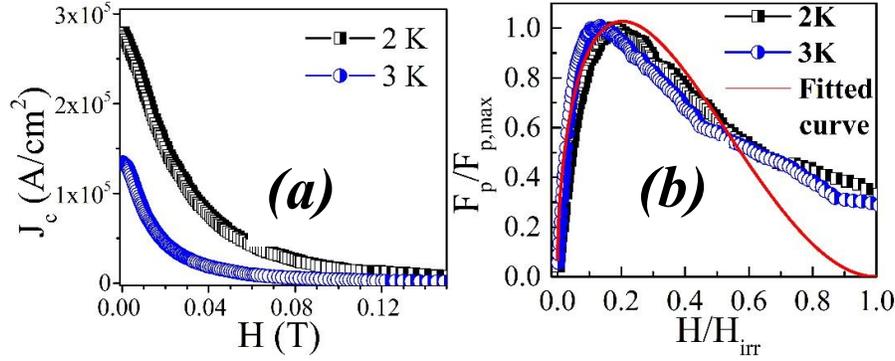


Figure 3. (a) Magnetic field dependence of critical current density ( $J_c$ ) for  $V_{0.001}NbSe_2$  at 2K and 3K (b) Normalized flux pinning force  $f_p = F_p/F_{p,max}$  shown as a function of reduced field  $H/H_{irr}$  at 2K and 3K temperatures.

Moreover, such a high value of  $J_c$  in  $V_{0.001}NbSe_2$  indicates the weak pinning phenomena due to the presence of V impurities. Depending on the size of the material and direction of magnetic field, the magnetization factor can be evaluated using the formula [14],

$$N = 1 - \tanh\sqrt{0.36b/a}, \quad (2)$$

Where  $a$  and  $b$  are the width and thickness of the sample. Here the estimated demagnetization factor for  $V_{0.001}NbSe_2$  is 0.68, which is almost similar with  $Cu_xNbSe_2$  as reported by Luo et. al [5]. Further, the pinning mechanism is investigated using Kramer's scaling law and Dew Hugh's scaling law of pinning force density.  $F_p$  was evaluated using the equation,

$$F_p = \mu_0 H \times J_c, \quad (3)$$

Fig. 3 (b) shows the normalized pinning force density ( $f_p = F_p/F_{p,max}$ ) as a function of reduced field ( $h = H/H_{irr}$ ) at 2K. To elucidate the contribution of the different pinning centers in the  $F_p$ , Dew-Hughes proposed a scaling rule  $f(h) \propto h^p(1-h)^q$ [15]. According to the Dew-Hughes model,  $p = 0.5$  and  $q=2$  reveal the surface pinning mechanism and  $p=1$  and  $q=2$  define the point pinning mechanism. In order to shed light on the geometry of pinning center in these samples, the normalized pinning force is fitted here using the following equation,

$$f(h) = a h^{0.5} (1-h)^2 + b h (1-h)^2 \quad (4)$$

where  $a$  and  $b$  are the fitting parameters. The normalized  $F_p$  curves are well fitted with eq. (4) as shown in Fig. 3 (b). The fitting parameters indicate that the surface pinning dominates over the point pinning mechanism. The V impurities act here as point pinning centers. Dew Hughes also proposed that  $h_{max} = 0.33$  and  $0.2$  correspond to the point core pinning and surface pinning, respectively. Thus,  $h_{max} = 0.2$  in the  $V_{0.001}NbSe_2$  indicates that the surface core pinning mechanism is the dominating pinning center. There is also a clear deviation of  $f_p$  vs  $h$  curves from the fitted plot at higher magnetic fields, which refers to the onset of the flux creep phenomenon.

## CONCLUSION

The pinning mechanism and the  $J_c$  characteristic are investigated intensively by studying the magnetization properties of  $NbSe_2$  single crystal. V atom depresses the superconductivity but  $J_c$  is improved at low magnetic field due to the point pinning centers. The maximum of the reduced field ( $h_{max}$ ) is observed at 0.2, indicating that the surface pinning mechanism is the dominating one. Both surface and point pinning mechanisms participate in the pinning mechanism of  $V_{0.001}NbSe_2$ .

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